

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









# **Smart "Expandable" range without display XB10 Smart Part number 88974132**



- Efficient and economical version, without display or keys setting
- Allow the use of the entire library of specific functions blocs of the software workshop
- Extended temperature range (-30 °C →+70 °C)
   Analogue inputs 0-10 VDC, Potentiometer, NTC, LDR (0-20 mA/Pt100 with converters)
- Open to XN network communication extensions, digital I/O, analogue, Pt100 extensions

Dard	mi	ım	ho	

Type	Inputs	Outputs	Supply
88974132 XB10 Smart	6 digital (including 4 analogue)	4 solid state 0.5 A (including 1 PWM)	24 V DC

## **Specifications**

<u> </u>	XD, XB, XR and XE product types
Certifications	CE, UL, CSA, GL
Conformity to standards (with the low voltage directive	IEC/EN 61131-2 (Open equipment)
and EMC directive)	IEC/EN 61131-2 (Zone B) IEC/EN 61000-6-2,
	IEC/EN 61000-6-2,
	IEC/EN 61000-6-4
	(*) Except configuration (88 970 1.1 or 88 970 1.2) + (88 970 250 or 88 970 270) + 88 970 241 class A (class B in a metal enclosure
Earthing	Not included
Protection rating	In accordance with IEC/EN 60529:
	IP40 on front panel
	IP20 on terminal block
Overvoltage category	3 in accordance with IEC/EN 60664-1
Pollution	Degree : 2 in accordance with IEC/EN 61131-2
Max operating Altitude	Operation: 2000 m
	Transport : 3048 m
Mechanical resistance	Immunity to vibrations IEC/EN 60068-2-6, test Fc
	Immunity to shock IEC/EN 60068-2-27, test Ea
Resistance to electrostatic discharge	Immunity to ESD
	IEC/EN 61000-4-2, level 3
Resistance to HF interference	Immunity to radiated electrostatic fields
	IEC/EN 61000-4-3
	Immunity to fast transients (burst immunity)
	IEC/EN 61000-4-4, level 3
	Immunity to shock waves IEC/EN 61000-4-5
	Radio frequency in common mode
	TEC/EN 61000-4-6, level 3
	Voltage dips and breaks (AC)
	IEC/EN 61000-4-11
	Immunity to damped oscillatory waves
	IEC/EN 61000-4-12
Conducted and radiated emissions	Class B (*) in accordance with EN 55022, EN 55011 (CISPR22, CISPR11) group 1
	(*) Except configuration (88 970 1.1 or 88 970 1.2) +
	(88 970 250 or 88 970 270) + 88 970 241 class A (class B in a metal enclosure)
Operating temperature	-20 →+70 °C
	except CB and XB versions in VDC: -30 →+70 °C (+40 °C in a non-ventilated enclosure)
	in accordance with IEC/EN 60068-2-1 and IEC/EN 60068-22
Storage temperature	-40 →+80 °C in accordance with IEC/EN 60068-2-1 and
D 1 / 2 / 2 / 2 / 2 / 2 / 2 / 2 / 2 / 2 /	IEC/EN 60068-2-2
Relative humidity	95 % max. (no condensation or dripping water) in accordance with IEC/EN 60068-2-30
Manustina	
Mounting	On symmetrical DIN rail, 35 x 7.5 mm and 35 x 15 mm, or on panel (2 x Ø 4 mm)
Screw terminals connection capacity	Flexible wire with ferrule =
	1 conductor : 0.25 to 2.5 mm <sup>2</sup> (AWG 24AWG 14)
	2 conductors 0.25 to 0.75 mm <sup>2</sup> (AWG 24AWG 18)
	Semi-rigid wire =
	1 conductor : 0.2 to 2.5 mm <sup>2</sup> (AWG 25AWG 14)
	Rigid wire =
	1 conductor : 0.2 to 2.5 mm <sup>2</sup> (AWG 25AWG 14)
	2 conductors 0.2 to 1.5 mm <sup>2</sup> (AWG 25AWG 16)
	Tightening torque =
	0.5 N.m (4.5 lb-in) (tighten using screwdriver diam. 3.5 mm)
	Also valid for spring cage connectors (ref 88 970 313 and 88 970 317 for the RBT range)

02/11/2015 www.crouzet.com

_	and the second second	
General	characteristics	

Operating temperature	-30 ->+70 °C (DC) ; -20 ->+70 °C (AC)
Operating factor	100 % (6 A relays)
	66 % (8 A relays)
Storage temperature	-30 →+80 °C

Processin	g characteristics of	CB, CD, XD	& XB product ty	pes
-----------	----------------------	------------	-----------------	-----

Programming method Programming method Program size  8 Kb : 350 typical blocks, 64 macros maximum, 256 blocks maximum per macro or 120 lines in Ladder Program memory Program memory Flash EEPROM Bemovable memory Back-up time in the event of power failure Program and settings in the controller : 10 years Program and settings in the plug-in memory : 10 years Data memory : 10 years Cycle time PBD : 6 → 90 ms (typically 20 ms) Ladder : typically 20 ms Input acquisition time : 1 to 2 cycle times Clock data retention 10 years (lithium battery) at 25 °C Clock drift Drift < 12 min/year (at 25 °C) 6 s/month (at 25 °C with user-definable correction of drift) Timer block accuracy Start up time on power up  CD, XD : Display with 4 lines of 18 characters 18 characters 19 cycle diversimal seximum per macro 19 cycle time solves maximum per macro 10 years 11 years 11 years 12 years 13 years 14 years 15 years 16 years 17 years 18 years 18 years 19 years 19 years 19 years 11 years 10 years 11 years 11 years 12 years 13 years 14 years 15 years 16 years 16 years 16 years 17 years 18 years 19 years 10 year		Todosoning characteriotics of object, Ab product types		
Program size  8 Kb : 350 typical blocks, 64 macros maximum, 256 blocks maximum per macro or 120 lines in Ladder  Program memory Flash EEPROM  Removable memory Back-up time in the event of power failure Program and settings in the controller : 10 years Program and settings in the plug-in memory : 10 years Data memory : 10 years  Cycle time FBD : 6 →90 ms (typically 20 ms) Ladder : typically 20 ms Ladder : typically 20 ms Input acquisition time : 1 to 2 cycle times  Clock data retention 10 years (lithium battery) at 25 °C Clock drift Drift < 12 min/year (at 25 °C) 6 s/month (at 25 °C with user-definable correction of drift)  Timer block accuracy 1 % ± 2 cycle times	LCD display	CD, XD : Display with 4 lines of 18 characters		
or 120 lines in Ladder  Program memory Flash EEPROM  Removable memory EEPROM  Back-up time in the event of power failure Program and settings in the controller : 10 years Program and settings in the plug-in memory : 10 years Program and settings in the plug-in memory : 10 years Data memory : 10 years  Cycle time FBD : 6 → 90 ms (typically 20 ms) Ladder : typically 20 ms Ladder : typically 20 ms (Clock data retention Input acquisition time : 1 to 2 cycle times  Clock data retention Drift < 12 min/year (at 25 °C) 6 s/month (at 25 °C with user-definable correction of drift)  Timer block accuracy 1 % ± 2 cycle times	Programming method	Function blocks / SCF (Grafcet) or Ladder		
Program memory Flash EEPROM  Removable memory EEPROM  Data memory 368 bit/200 words  Back-up time in the event of power failure Program and settings in the controller : 10 years Program and settings in the plug-in memory : 10 years Data memory : 10 years Data memory : 10 years Program and settings in the plug-in memory : 10 years Data memory : 10 years Ladder : typically 20 ms Input acquisition time : 1 to 2 cycle times Clock data retention Drift < 12 min/year (at 25 °C) 6 s/month (at 25 °C with user-definable correction of drift) Timer block accuracy 1 % ± 2 cycle times	Program size	8 Kb : 350 typical blocks, 64 macros maximum, 256 blocks maximum per macro		
Program memory       Flash EEPROM         Removable memory       368 bit/200 words         Back-up time in the event of power failure       Program and settings in the controller : 10 years		or		
Removable memory         Data memory       368 bit/200 words         Back-up time in the event of power failure       Program and settings in the controller : 10 years         Program and settings in the plug-in memory : 10 years         Data memory : 10 years         Cycle time       FBD : 6 →90 ms (typically 20 ms)         Ladder : typically 20 ms         Ladder : typically 20 ms         Input acquisition time : 1 to 2 cycle times         Clock data retention       10 years (lithium battery) at 25 °C         Clock drift       Drift < 12 min/year (at 25 °C)         6 s/month (at 25 °C with user-definable correction of drift)         Timer block accuracy       1 % ± 2 cycle times		120 lines in Ladder		
Data memory       368 bit/200 words         Back-up time in the event of power failure       Program and settings in the controller : 10 years         Program and settings in the plug-in memory : 10 years         Data memory : 10 years         Cycle time       FBD : 6 →90 ms (typically 20 ms)         Ladder : typically 20 ms         Ladder : typically 20 ms         Input acquisition time : 1 to 2 cycle times         Clock data retention       10 years (lithium battery) at 25 °C         Clock drift       Drift < 12 min/year (at 25 °C)         6 s/month (at 25 °C with user-definable correction of drift)         Timer block accuracy       1 % ± 2 cycle times	Program memory	Flash EEPROM		
Back-up time in the event of power failure       Program and settings in the controller : 10 years         Program and settings in the plug-in memory : 10 years         Data memory : 10 years         Cycle time       FBD : 6 →90 ms (typically 20 ms)         Ladder : typically 20 ms         Input acquisition time : 1 to 2 cycle times         Clock data retention       10 years (lithium battery) at 25 °C         Clock drift       Drift < 12 min/year (at 25 °C)         6 s/month (at 25 °C with user-definable correction of drift)         Timer block accuracy       1 % ± 2 cycle times	Removable memory	EEPROM		
Program and settings in the plug-in memory : 10 years Data memory : 10 years  Cycle time  FBD : 6 → 90 ms (typically 20 ms) Ladder : typically 20 ms  Input acquisition time : 1 to 2 cycle times  Clock data retention  10 years (lithium battery) at 25 °C  Clock drift  Drift < 12 min/year (at 25 °C) 6 s/month (at 25 °C with user-definable correction of drift)  Timer block accuracy  1 % ± 2 cycle times	Data memory	368 bit/200 words		
Data memory : 10 years  Cycle time  FBD : 6 →90 ms (typically 20 ms) Ladder : typically 20 ms  Input acquisition time : 1 to 2 cycle times  Clock data retention  10 years (lithium battery) at 25 °C  Clock drift  Drift < 12 min/year (at 25 °C) 6 s/month (at 25 °C with user-definable correction of drift)  Timer block accuracy  1 % ± 2 cycle times	Back-up time in the event of power failure	Program and settings in the controller : 10 years		
Cycle time     FBD : 6 → 90 ms (typically 20 ms)       Ladder : typically 20 ms       Response time     Input acquisition time : 1 to 2 cycle times       Clock data retention     10 years (lithium battery) at 25 °C       Clock drift     Drift < 12 min/year (at 25 °C)       6 s/month (at 25 °C with user-definable correction of drift)       Timer block accuracy     1 % ± 2 cycle times		Program and settings in the plug-in memory: 10 years		
Ladder : typically 20 ms  Response time Input acquisition time : 1 to 2 cycle times  Clock data retention 10 years (lithium battery) at 25 °C  Clock drift Drift < 12 min/year (at 25 °C) 6 s/month (at 25 °C with user-definable correction of drift)  Timer block accuracy 1 % ± 2 cycle times		Data memory : 10 years		
Response time     Input acquisition time : 1 to 2 cycle times       Clock data retention     10 years (lithium battery) at 25 °C       Clock drift     Drift < 12 min/year (at 25 °C)       6 s/month (at 25 °C with user-definable correction of drift)       Timer block accuracy     1 % ± 2 cycle times	Cycle time	FBD : 6 →90 ms (typically 20 ms)		
Clock data retention     10 years (lithium battery) at 25 °C       Clock drift     Drift < 12 min/year (at 25 °C)       6 s/month (at 25 °C with user-definable correction of drift)       Timer block accuracy     1 % ± 2 cycle times		Ladder: typically 20 ms		
Clock drift  Drift < 12 min/year (at 25 °C) 6 s/month (at 25 °C with user-definable correction of drift)  Timer block accuracy  1 % ± 2 cycle times	Response time	Input acquisition time: 1 to 2 cycle times		
6 s/month (at 25 °C with user-definable correction of drift)  Timer block accuracy  1 % ± 2 cycle times	Clock data retention	10 years (lithium battery) at 25 °C		
Timer block accuracy 1 % ± 2 cycle times	Clock drift	Drift < 12 min/year (at 25 °C)		
·		6 s/month (at 25 °C with user-definable correction of drift)		
Start up time on power up < 1,2 s	Timer block accuracy	1 % ± 2 cycle times		
	Start up time on power up	< 1,2 s		

## Characteristics of products with AC power supplied

Supp	ly

Supply		
Nominal voltage	24 V AC	100 →240 V AC
Operating limits	-15 % / +20 % or 20.4 V AC→28.8 V AC	-15 % / +10 % or 85 V AC→264 V AC
Supply frequency range	50/60 Hz (+4 % / -6 %) or 47 →53 Hz/57 →63 Hz	50/60 Hz (+ 4 % / - 6 %) or 47 →53 Hz/57 →63 Hz
Immunity from micro power cuts	10 ms (repetition 20 times)	10 ms (repetition 20 times)
Max. absorbed power	CB12-CD12-XD10-XB10 : 4 VA CB20-CD20 : 6 VA XD10-XB10 with extension : 7.5 VA XD26-XB26 : 7.5 VA XD26-XB26 with extension : 10 VA	CB12-CD12-XD10-XB10: 7 VA CB20-CD20: 11 VA XD10-XB10 with extension: 12 VA XD26-XB26: 12 VA XD26-XB26 with extension: 17 VA
Isolation voltage	1780 V AC	1780 V AC

## Inputs

inputs		
Input voltage	24 V AC (-15 % / +20 %)	100 →240 V AC (-15 % / +10 %)
Input current	4.4 mA @ 20.4 V AC 5.2 mA @ 24.0 V AC 6.3 mA @ 28.8 V AC	0.24 mA @ 85 V AC 0.75 mA @ 264 V AC
Input impedance	4.6 kΩ	350 kΩ
Logic 1 voltage threshold	≥ 14 V AC	≥ 79 V AC
Making current at logic state 1	> 2 mA	> 0.17 mA
Logic 0 voltage threshold	≤5 V AC	≤ 20 V AC (≤ 28 V AC : XE10, XR06, XR10, XR14)
Release current at logic state 0	< 0.5 mA	< 0.5 mA
Response time with LADDER programming	50 ms State 0 →1 (50/60 Hz)	50 ms State 0 →1 (50/60 Hz)
Response time with function blocks programming	Configurable in increments of 10 ms 50 ms min. up to 255 ms State $0 \rightarrow 1 (50/60 \text{ Hz})$	Configurable in increments of 10 ms 50 ms min. up to 255 ms State 0 $\rightarrow$ 1 (50/60 Hz)
Maximum counting frequency	In accordance with cycle time (Tc) and input response time (Tr) : 1/ ( (2 x Tc) + Tr)	In accordance with cycle time (Tc) and input response time (Tr) : 1/ ( $(2 \times Tc) + Tr)$
Sensor type	Contact or 3-wire PNP	Contact or 3-wire PNP
Input type	Resistive	Resistive
Isolation between power supply and inputs	None	None
Isolation between inputs	None	None
Protection against polarity inversions	Yes	Yes
Status indicator	On LCD screen for CD and XD	On LCD screen for CD and XD

# Characteristics of relay outputs common to the entire range

Max. breaking voltage	5 →30 V DC 24 →250 V AC
Breaking current	CB-CD-XD10-XB10-XR06-XR10 : 8 A XD26-XB26 : 8 x 8 A relays, 2 x 5 A relays XE10 : 4 x 5 A relays XR14 : 4 x 8 A relays, 2 x 5 A relays RBT (Removable Terminal Blocks) versions : verify the maximum current according to the type of connection used
Electrical durability for 500 000 operating cycles	Utilization category DC-12: 24 V, 1.5 A Utilization category DC-13: 24 V (L/R = 10 ms), 0.6 A Utilization category AC-12: 230 V, 1.5 A Utilization category AC-15: 230 V, 0.9 A
Max. Output Common Current	12 A for O8, O9, OA
Minimum switching capacity	10 mA (at minimum voltage of 12 V)
Minimum load	12 V, 10 mA

02/11/2015 www.crouzet.com

02/11/2015			www.crouzet.com	
Maximum rate	Off load : 10 Hz			
A		At operating current : 0.1 Hz		
Mechanical life  Voltage for withstanding shocks	10,000,000 (operations) In accordance with IEC/EN 60947-1 and IEC	/EN 60664 1 · 4 kV		
Off-cycle response time	Make 10 ms	/EN 00004-1 . 4 KV		
on dyale responde anno	Release 5 ms			
Built-in protections	Against short-circuits : None			
	Against overvoltages and overloads : None			
Status indicator	On LCD screen for CD and XD			
Characteristics of product with DC power sup	olied			
Supply				
Nominal voltage	12 V DC	24 V DC		
Operating limits	-13 % / +20 %	-20 % / +25 %	DC (including ripple)	
Immunity from micro power cuts	or 10.4 V DC→14.4 V DC (including ripple) ≤ 1 ms (repetition 20 times)	or 19.2 V DC→30 V ≤ 1 ms (repetition 20	· • · · · · · · · · · · · · · · · · · ·	
Max. absorbed power	CB12 with solid state outputs: 1.5 W CD12: 1.5 W CD20: 2.5 W XD26-XB26: 3 W XD26-XB26 with extension: 5 W XD26 with solid state outputs: 2.5 W	CB12-CD12-CD20 w XD10-XB10 with rela XD26-XB26 with soli CB20-CD20 with rela XD26 with relay out XD10-XB10 with ext XD26-XB26 with ext	rith solid state outputs - XD10-XB10 with solid state outputs : 3 W ay outputs : 4 W d state outputs : 5 W ay outputs : 6 W outs : 6 W ension : 8 W	
Protection against polarity inversions	Yes	Yes		
Digital inputs (I1 to IA and IH to IY)				
Input voltage	12 V DC (-13 % / +20 %)		24 V DC (-20 % / +25 %)	
Input current	3.9 mA @ 10.44 V DC 4.4 mA @ 12.0 V DC		2.6 mA @ 19.2 V DC 3.2 mA @ 24 V DC	
	5.3 mA @ 14.4 VDC		4.0 mA @ 30.0 VDC	
Input impedance	2.7 kΩ		7.4 kΩ	
Logic 1 voltage threshold	≥7 V DC		≥ 15 V DC	
Making current at logic state 1	≥ 2 mA		≥ 2.2 mA	
Logic 0 voltage threshold	≤3 V DC		≤5 V DC	
Release current at logic state 0	< 0.9 mA		< 0.75 mA	
Response time  Maximum counting frequency	1 →2 cycle times + 6 ms  Inputs I1 & I2 : FBD (up to 6 k Hz) & Ladder Inputs I3 to IA & IH to IY : In accordance with input response time (Tr): 1/((2 x Tc) + Tr)	h cycle time (Tc) and	1 →2 cycle times + 6 ms  Inputs I1 & I2 : FBD (up to 6 k Hz) & Ladder (1 k Hz)  Inputs I3 to IA & IH to IY : In accordance with cycle time (Tc) and input response time (Tr) : 1/ ( (2 x Tc) + Tr)	
Sensor type	Contact or 3-wire PNP		Contact or 3-wire PNP	
Conforming to IEC/EN 61131-2	Type 1		Type 1	
Input type	Resistive		Resistive	
Isolation between power supply and inputs  Isolation between inputs	None None		None None	
Protection against polarity inversions			Yes	
Status indicator	On LCD screen for CD and XD		On LCD screen for CD and XD	
Analogue or digital inputs (IB to IG)				
CB12-CD12-XD10-XB10	4 inputs IB →IE		4 inputs IB →IE	
CB20-CD20-XB26-XD26	6 inputs IB →IG		6 inputs IB →IG	
Inputs used as analogue inputsonly in FBD				
Measurement range	$(0 \rightarrow 10 \text{ V}) \text{ or } (0 \rightarrow \text{V power supply})$		$(0 \rightarrow 10 \text{ V}) \text{ or } (0 \rightarrow \text{V power supply})$	
Input impedance	14 kΩ		12 kΩ	
Input voltage	14.4 V DC max.		30 V DC max.	
Value of LSB	14 mV		29 mV	
Input type Resolution	Common mode		Common mode  10 bit at max. input voltage	
Conversion time	10 bit at max. input voltage  Controller cycle time		Controller cycle time	
Accuracy at 25 °C	± 5 %		± 5 %	
Accuracy at 55 °C	± 6.2 %		± 6.2 %	
Repeat accuracy at 55 °C	± 2 %		± 2 %	
Isolation between analogue channel and power supp			None	
Cable length	10 m maximum, with shielded cable (sensor	not isolated)	10 m maximum, with shielded cable (sensor not isolated)	
Protection against polarity inversions  Potentiometer control	Yes 2.2 kΩ/0.5 W (recommended) 10 kΩ max.		Yes 2.2 $k\Omega/0.5$ W (recommended) 10 $k\Omega$ max.	
Inputs used as digital inputs				
Input voltage	12 V DC (-13 % / +20 %)		24 V DC (-20 % / +25 %)	
Input current	0.7 mA @ 10.44 VDC 0.9 mA @ 12.0 VDC 1.0 mA @ 14.4VDC		1.6 mA @ 19.2 VDC 2.0 mA @ 24.0 V DC 2.5 mA @ 30.0 VDC	
Input impedance	1.0 πΑ @ 14.4 ν D C		2.5 ΠΑ @ 30.0 VDC 12 kΩ	
Logic 1 voltage threshold	≥7 V DC		≥ 15 VDC	
Making current at logic state 1	≥ 0.5 mA		≥ 1.2 mA	
Logic 0 voltage threshold	≤3VDC		≤5 V DC	
Release current at logic state 0	≤ 0.2 mA		≤ 0.5 mA	
Response time	1 →2 cycle times		1 →2 cycle times	
Maximum counting frequency in FBD	In accordance with cycle time (Tc) and input 1/ ((2 x Tc) + Tr)	t response time (Tr):	In accordance with cycle time (Tc) and input response time (Tr) : 1/ ( (2 x Tc) + Tr)	
Sensor type	Contact or 3-wire PNP		Contact or 3-wire PNP	
Conforming to IEC/EN 61131-2	Type 1 Resistive		Type 1	
Input type	nesistive		Resistive	

02/11/2015 www.crouzet.com

Isolation between power supply and inputs None None

None

None

isolation between inputs	Notic	None
Protection against polarity inversions	Yes	Yes
Status indicator	On LCD screen for CD and XD	On LCD screen for CD and XD
Characteristics of relay outputs common to th	e entire range	
Max. breaking voltage	5 →30 V DC 24 →250 V AC	
Max. Output Common Current	12A (10A UL) for O8, O9, OA	
Breaking current	CB-CD-XD10-XB10-XR06-XR10 : 8 A XD26-XB26 : 8 x 8 A relays, 2 x 5 A relays XE10 : 4 x 5 A relays XR14 : 4 x 8 A relays, 2 x 5 A relays	
Electrical durability for 500 000 operating cycles	Utilization category DC-12 : 24 V, 1.5 A Utilization category DC-13 : 24 V (L/R = 10 ms), 0.6 A Utilization category AC-12 : 230 V, 1.5 A Utilization category AC-15 : 230 V, 0.9 A	
Minimum switching capacity	10 mA (at minimum voltage of 12 V)	
Minimum load	12 V, 10 mA	
Maximum rate	Off load : 10 Hz At operating current : 0.1 Hz	
Mechanical life	10,000,000 (operations)	
Voltage for withstanding shocks	In accordance with IEC/EN 60947-1 and IEC/EN 60664-1: 4 kV	
Off-cycle response time	Make 10 ms Release 5 ms	
Built-in protections	Against short-circuits : None Against overvoltages and overloads : None	
Status indicator	On LCD screen for CD and XD	

Digital / PWM solid state output

Digital / P Wivi Solid State output				
PWM solid state output*	CB12 : O4 XD26 : O4 →O7	CD12-XD10-XB10 : O4 CD20-XD26-XB26 : O4 →O7		
* Only available with "FBD" programming language	* Only available with "FBD" programming language			
Breaking voltage	10.4 →30 V DC	19.2 →30 V DC		
Nominal voltage	12-24 VDC	24 V DC		
Nominal current	0.5 A	0.5 A		
Max. breaking current	0,625 A	0,625 A		
Voltage drop	≤ 2 V for I = 0.5 A (at state 1)	≤ 2 V for I = 0.5 A (at state 1)		
Response time	Make ≤ 1 ms Release ≤ 1 ms	Make ≤ 1 ms Release ≤ 1 ms		
Operating frequency	1 Maximum on inductive load	1 Maximum on inductive load		
Built-in protections	Against overloads and short-circuits: Yes Against overvoltages (*): Yes Against inversions of power supply: Yes (*) In the absence of a volt-free contact between the logic controller output and the load	Against overloads and short-circuits: Yes Against overvoltages (*): Yes Against inversions of power supply: Yes (*) In the absence of a volt-free contact between the logic controller output and the load		
Min. load	1 mA	1 mA		
Maximum incandescent load	0,2 A / 12 V DC 0,1 A / 24 V DC	0,1 A / 24 V DC		
Galvanic isolation	No	No		
PWM frequency	14.11 Hz 56.45 Hz 112.90 Hz 225.80 Hz 451.59 Hz 1806.37 Hz	14.11 Hz 56.45 Hz 112.90 Hz 225.80 Hz 451.59 Hz 1806.37 Hz		
PWM cyclic ratio	0 →100 % (256 steps for CD, XD and 1024 steps for XA)	0 →100 % (256 steps for CD, XD and 1024 steps for XA)		
Max. Breaking current PWM	50 mA	50 mA		
Max. cable length PWM	20 m	20 m		
PWM accuracy at 120 Hz	< 5 % (20 % →80 %) load at 10 mA	< 5 % (20 % →80 %) load at 10 mA		
PWM accuracy at 500 Hz	10.07 (00.07 00.07)	< 10 % (20 % →80 %) load at 10 mA		
F WIVI accuracy at 500 Hz	< 10 % (20 % →80 %) load at 10 mA	< 10 % (20 % →80 %) load at 10 mA		

## Accessories

Туре	Description	Code
M3 Soft	Multilingual programming software containing specific library functions (CD-ROM)	88970111
PA	EEPROM memory cartridge	88970108
PA	3 m serial link cable : PC →Millenium 3	88970102
PA	USB cable 3 m : PC →Millenium 3	88970109
PA	Millenium 3 interface →Bluetooth® (class A 10 m)	88970104

## Comments

\* to be marketed 1st quarter 2006

## Dimensions (mm)

#### XD10 Smart

02/11/2015 www.crouzet.com

